# 500 Watt Peak Power MiniMOSORB™ Zener Transient Voltage Suppressors

### **Unidirectional\***

The SA5.0A series is designed to protect voltage sensitive components from high voltage, high energy transients. They have excellent clamping capability, high surge capability, low zener impedance and fast response time. The SA5.0A series is supplied in ON Semiconductor's exclusive, cost-effective, highly reliable Surmetic™ axial leaded package and is ideally-suited for use in communication systems, numerical controls, process controls, medical equipment, business machines, power supplies and many other industrial/consumer applications.

### **Specification Features:**

- Working Peak Reverse Voltage Range 5 to 170 V
- Peak Power 500 Watts @ 1 ms
- ESD Rating of Class 3 (>16 KV) per Human Body Model
- Maximum Clamp Voltage @ Peak Pulse Current
- Low Leakage < 1 μA above 8.5 V
- UL 497B for Isolated Loop Circuit Protection
- Maximum Temperature Coefficient Specified
- Response Time is typically < 1 ns

### **Mechanical Characteristics:**

**CASE:** Void-free, Transfer-molded, Thermosetting plastic

FINISH: All external surfaces are corrosion resistant and leads are

readily solderable

### MAXIMUM LEAD TEMPERATURE FOR SOLDERING: 230°C,

1/16" from the case for 10 seconds

**POLARITY:** Cathode indicated by polarity band.

**MOUNTING POSITION:** Any

### **MAXIMUM RATINGS**

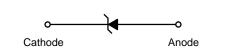
Rating	Symbol	Value	Unit
Peak Power Dissipation (Note 1.) @ T <sub>L</sub> ≤ 25°C	P <sub>PK</sub>	500	Watts
Steady State Power Dissipation @ T <sub>L</sub> ≤ 75°C, Lead Length = 3/8″	$P_{D}$	3.0	Watts
Derated above T <sub>L</sub> = 75°C		30	mW/°C
Thermal Resistance, Junction-to-Lead	$R_{ heta JL}$	33.3	°C/W
Forward Surge Current (Note 2.) @ T <sub>A</sub> = 25°C	I <sub>FSM</sub>	70	Amps
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	– 55 to +175	°C

- 1. Nonrepetitive current pulse per Figure 4 and derated above  $T_A = 25$  °C per Figure 2.
- 2. 1/2 sine wave (or equivalent square wave), PW = 8.3 ms, duty cycle = 4 pulses per minute



### ON Semiconductor™

### http://onsemi.com







L = Assembly Location SAxxxA = ON Device Code YY = Year WW = Work Week

### ORDERING INFORMATION

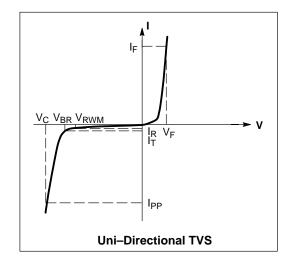
Device	Package	Shipping		
SAxxxA	Axial Lead	1000 Units/Box		
SAxxxARL	Axial Lead	5000/Tape & Reel		

Devices listed in *bold, italic* are ON Semiconductor **Preferred** devices. **Preferred** devices are recommended choices for future use and best overall value.

<sup>\*</sup>Please see SA5.0CA - SA170CA for Bidirectional devices.

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted, $V_F = 3.5$ V Max. @ $I_F$ (Note 4) = 35 A)

Symbol	Parameter				
I <sub>PP</sub> Maximum Reverse Peak Pulse Current					
V <sub>C</sub> Clamping Voltage @ I <sub>PP</sub>					
V <sub>RWM</sub>	Working Peak Reverse Voltage				
I <sub>R</sub>	Maximum Reverse Leakage Current @ V <sub>RWM</sub>				
V <sub>BR</sub>	Breakdown Voltage @ I <sub>T</sub>				
I <sub>T</sub>	Test Current				
ΘV <sub>BR</sub>	Maximum Temperature Variation of V <sub>BR</sub>				
I <sub>F</sub>	Forward Current				
V <sub>F</sub>	V <sub>F</sub> Forward Voltage @ I <sub>F</sub>				



### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted, V<sub>F</sub> = 3.5 V Max. @ I<sub>F</sub> (Note 4) = 35 A)

Device SA5.0A SA6.0A SA7.0A	Device Marking SA5.0A SA6.0A	V <sub>RWM</sub> (Note 1) Volts	I <sub>R</sub> @ V <sub>RWM</sub> μ <b>A</b>	V <sub>BR</sub>	(Note 2) (\	/olte)	@ <del>Լ</del>	ν <sub>c</sub>	I <sub>PP</sub>	OV.
SA5.0A SA6.0A	Marking SA5.0A SA6.0A				V <sub>BR</sub> (Note 2) (Volts)		ا ھ	۸C	'PP	$\Theta V_{BR}$
SA6.0A	SA6.0A	_	μΑ	Min	Nom	Max	mA	Volts	Α	mV/°C
		5	600	6.4	6.7	7	10	9.2	54.3	5
SA7.0A		6	600	6.67	7.02	7.37	10	10.3	48.5	5
	SA7.0A	7	150	7.78	8.19	8.6	10	12	41.7	6
SA7.5A	SA7.5A	7.5	50	8.33	8.77	9.21	1	12.9	38.8	7
SA8.0A	SA8.0A	8	25	8.89	9.36	9.83	1	13.6	36.7	7
SA8.5A	SA8.5A	8.5	5	9.44	9.92	10.4	1	14.4	34.7	8
SA9.0A	SA9.0A	9	1	10	10.55	11.1	1	15.4	32.5	9
SA10A	SA10A	10	1	11.1	11.7	12.3	1	17	29.4	10
SA11A	SA11A	11	1	12.2	12.85	13.5	1	18.2	27.4	11
SA12A	SA12A	12	1	13.3	14	14.7	1	19.9	25.1	12
SA13A	SA13A	13	1	14.4	15.15	15.9	1	21.5	23.2	13
SA14A	SA14A	14	1	15.6	16.4	17.2	1	23.2	21.5	14
SA15A	SA15A	15	1	16.7	17.6	18.5	1	24.4	20.6	16
SA16A	SA16A	16	1	17.8	18.75	19.7	1	26	19.2	17
SA17A	SA17A	17	1	18.9	19.9	20.9	1	27.6	18.1	19
SA18A	SA18A	18	1	20	21.05	22.1	1	29.2	17.2	20
SA20A	SA20A	20	1	22.2	23.35	24.5	1	32.4	15.4	23
SA22A	SA22A	22	1	24.4	25.65	26.9	1	35.5	14.1	25
SA24A	SA24A	24	1	26.7	28.1	29.5	1	38.9	12.8	28
SA26A	SA26A	26	1	28.9	30.4	31.9	1	42.1	11.9	30
SA28A	SA28A	28	1	31.1	32.75	34.4	1	45.4	11	31
SA30A	SA30A	30	1	33.3	35.05	36.8	1	48.4	10.3	36
SA33A	SA33A	33	1	36.7	38.65	40.6	1	53.3	9.4	39
SA36A	SA36A	36	1	40	42.1	44.2	1	58.1	8.6	41
SA40A	SA40A	40	1	44.4	46.55	49.1	1	64.5	7.8	46
SA43A	SA43A	43	1	47.8	50.3	52.8	1	69.4	7.2	50
SA45A	SA45A	45	1	50	52.65	55.3	1	72.7	6.9	52
SA48A	SA48A	48	1	53.3	56.1	58.9	1	77.4	6.5	56
SA51A	SA51A	51	1	56.7	59.7	62.7	1	82.4	6.1	61
SA58A	SA58A	58	1	64.4	67.8	71.2	1	93.6	5.3	70
SA60A	SA60A	60	1	66.7	70.2	73.7	1	96.8	5.2	71
SA64A	SA64A	64	1	71.1	74.85	78.6	1	103	4.9	76
SA70A	SA70A	70	1	77.8	81.9	86	1	113	4.4	85
SA78A	SA78A	78	1	86.7	91.25	95.8	1	126	4.0	95
SA90A	SA90A	90	1	100	105.5	111	1	146	3.4	110
SA100A	SA100A	100	1	111	117	123	1	162	3.1	123
SA110A	SA110A	110	1	122	128.5	135	1	177	2.8	133
SA120A	SA120A	120	1	133	140	147	1	193	2.5	146
SA130A	SA130A	130	1	144	151.5	159	1	209	2.4	158
SA150A	SA150A	150	1	167	176	185	1	243	2.1	184
SA160A	SA160A	160	1	178	187.5	197	1	259	1.9	196
	SA170A	170	1	189	199	209	1	275	1.8	208

- 1. MiniMOSORB™ transients suppressor is normally selected according to the maximum working peak reverse voltage (V<sub>RWM</sub>), which should be equal to or greater than the dc or continuous peak operating voltage level.

- V<sub>BR</sub> measured at pulse test current I<sub>T</sub> at an ambient temperature of 25°C.
   Surge current waveform per Figure 4 and derate per Figures 1 and 2.
   1/2 sine wave (or equivalent square wave), PW = 8.3 ms, duty cycle = 4 pulses per minute

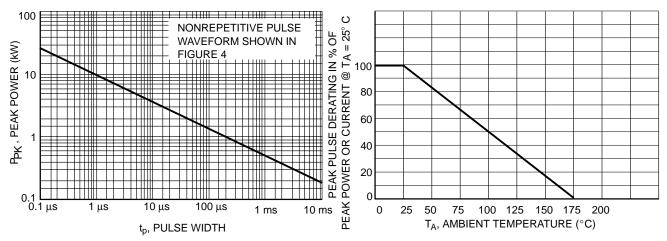


Figure 1. Pulse Rating Curve

Figure 2. Pulse Derating Curve

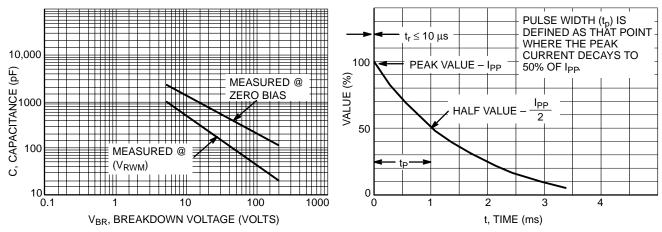


Figure 3. Capacitance versus Breakdown Voltage

Figure 4. Pulse Waveform

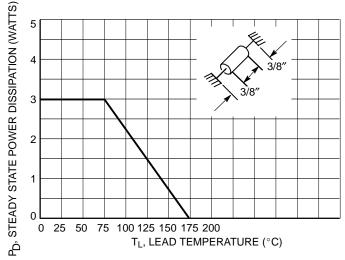


Figure 5. Steady State Power Derating

### **UL RECOGNITION\***

The entire series including the bidirectional CA suffix has *Underwriters Laboratory Recognition* for the classification of protectors (QVGV2) under the UL standard for safety 497B and File #E 116110. Many competitors only have one or two devices recognized or have recognition in a non-protective category. Some competitors have no recognition at all. With the UL497B recognition, our parts successfully passed several tests including Strike Voltage

Breakdown test, Endurance Conditioning, Temperature test, Dielectric Voltage-Withstand test, Discharge test and several more.

Whereas, some competitors have only passed a flammability test for the package material, we have been recognized for much more to be included in their protector category.

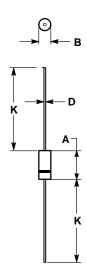
\*Applies to SA5.0A, CA - SA170A, CA.

### **OUTLINE DIMENSIONS**

# **Transient Voltage Suppressors – Axial Leaded**

# 500 Watt Peak Power MiniMOSORB™

### **MINI MOSORB** CASE 59-09 ISSUE R



- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
- 2. CONTROLLING DIMERSION. INCH. 3. 59-04 OBSOLETE, NEW STANDARD 59-09. 4. 59-03 OBSOLETE, NEW STANDARD 59-10. 5. ALL RULES AND NOTES ASSOCIATED WITH

- JEDEC DO-41 OUTLINE SHALL APPLY.

  6. POLARITY DENOTED BY CATHODE BAND.

  7. LEAD DIAMETER NOT CONTROLLED WITHIN F DIMENSION.

		INC	HES	MILLIN	IETERS	
	DIM	MIN	MAX	MIN	MAX	
	Α	0.228	0.299	5.80	7.60	
	В	0.102	0.142	2.60	3.60	
	D	0.028	0.034	0.71	0.86	
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